



Passage M1000

A 3D Photonic Interposer for AI

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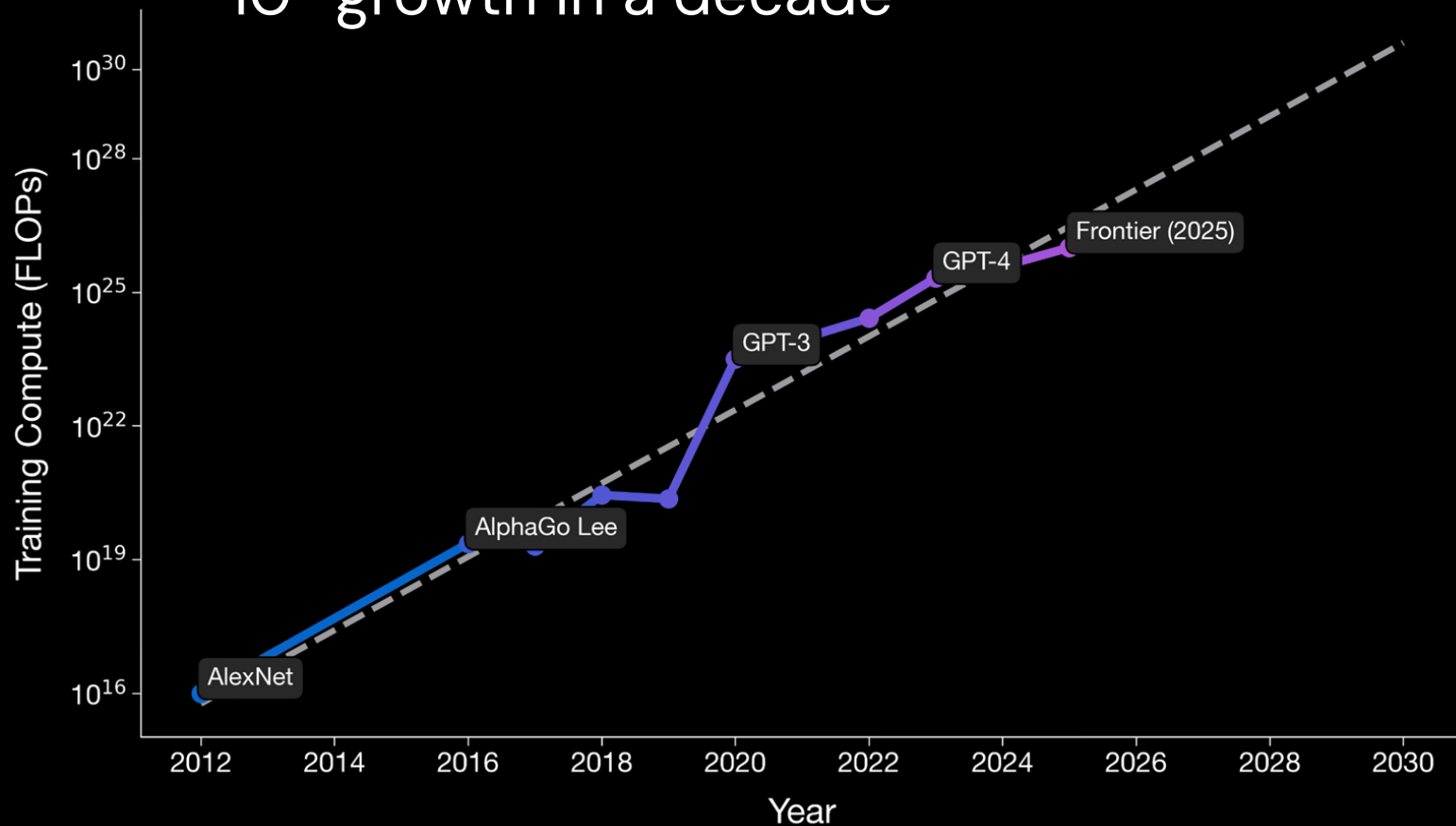
Hot Chips 2025



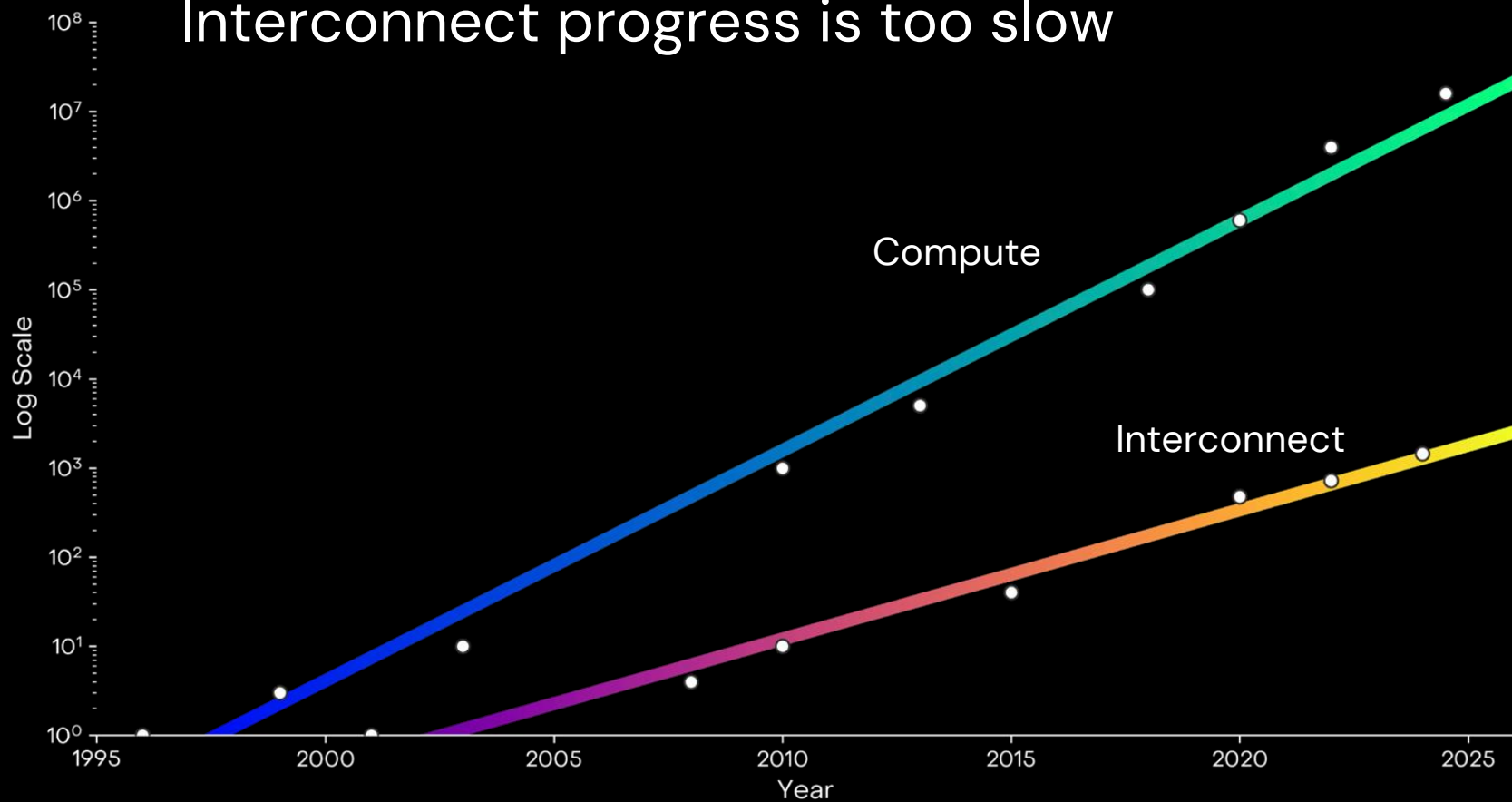
A decade of AI breakthroughs

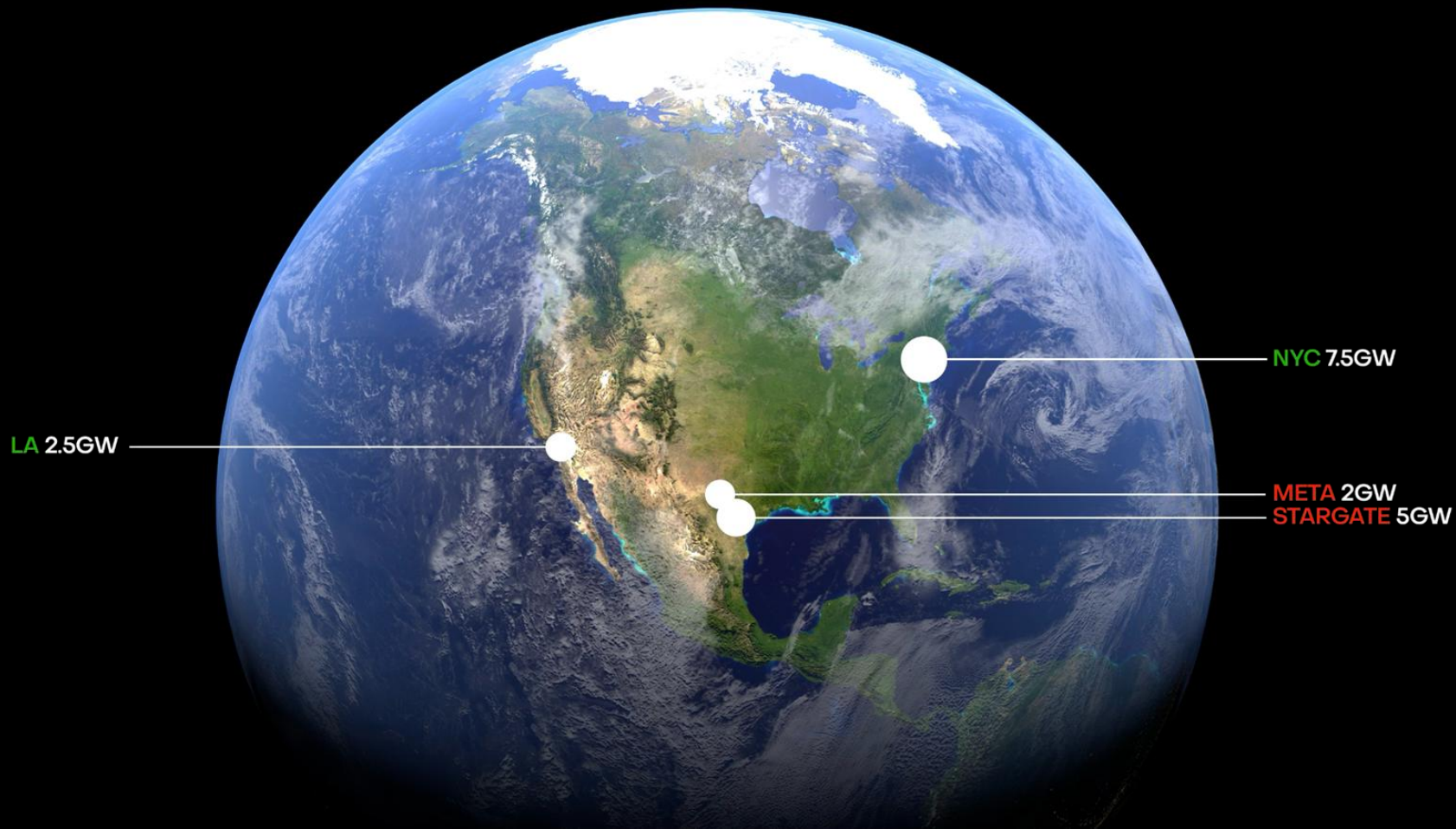


10^9 growth in a decade



Interconnect progress is too slow





The interconnect bottleneck

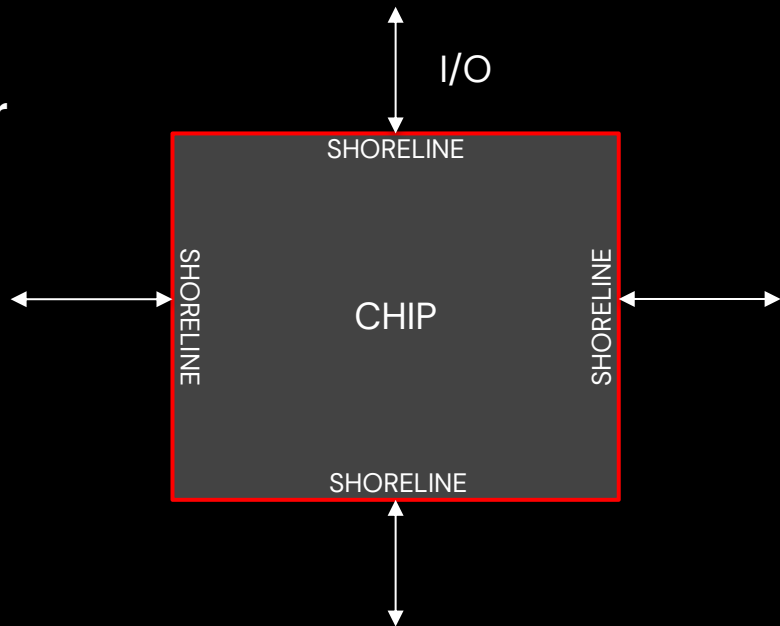
Communication happens at the chip **perimeter**

FLOPS $\propto$ Chip Area (L^2)

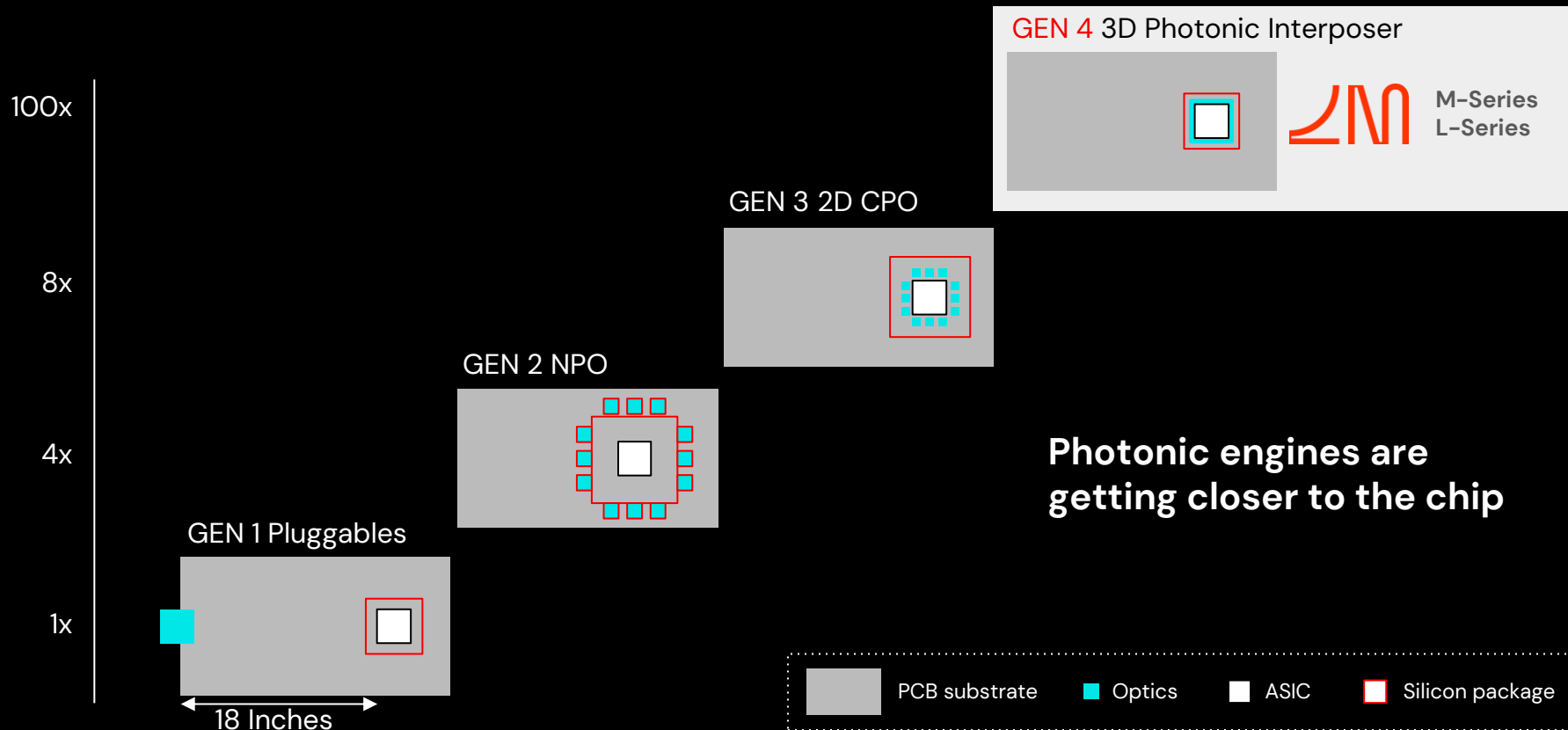
IO Bandwidth $\propto$ Chip Perimeter (L)

We need $>100\times$ the bandwidth.

A new paradigm is needed.



The promise of silicon photonics



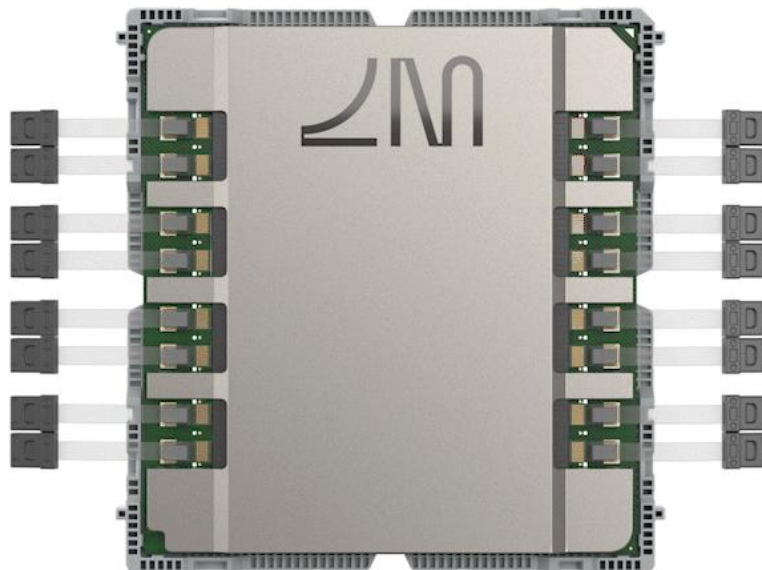
Our Solution

Passage M1000

3D Photonic Interposer

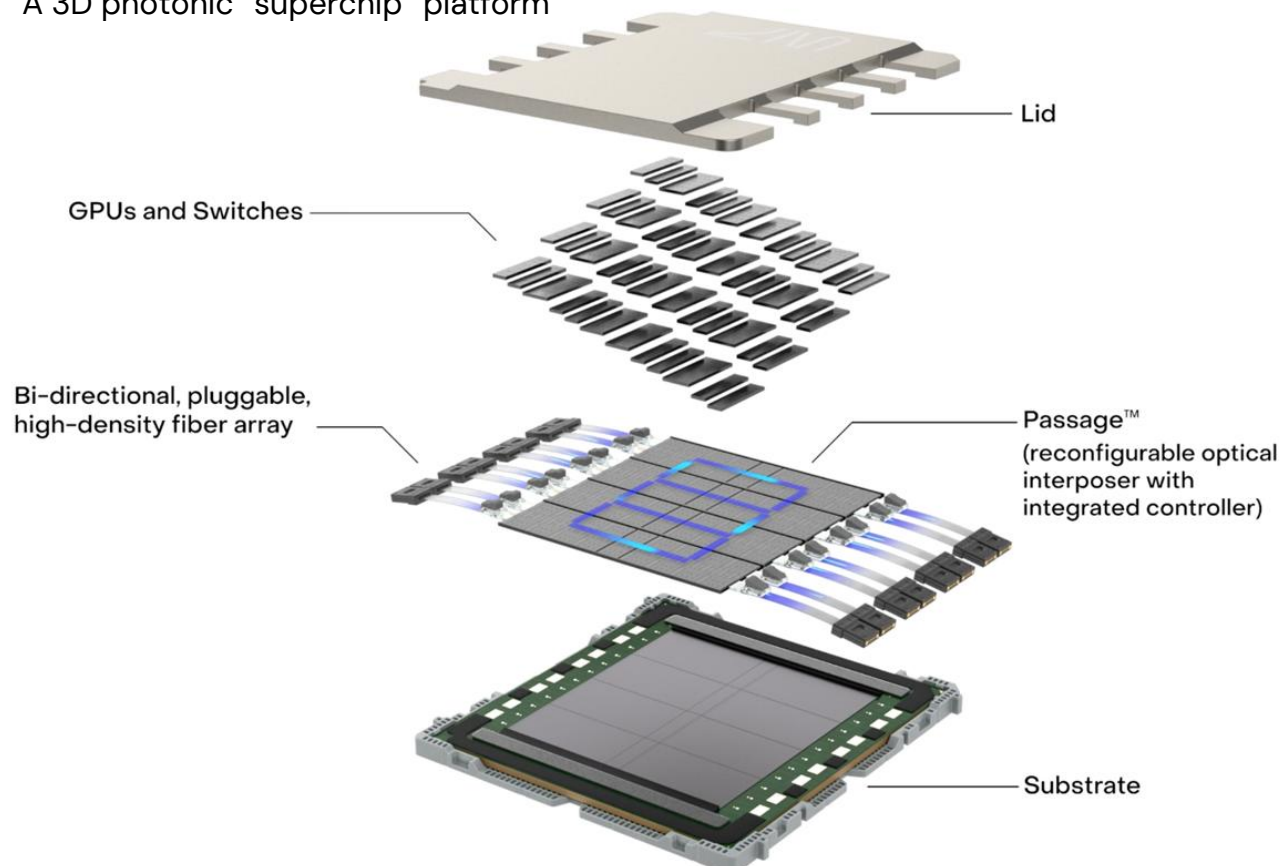
Passage M1000

A 3D photonic “superchip” platform

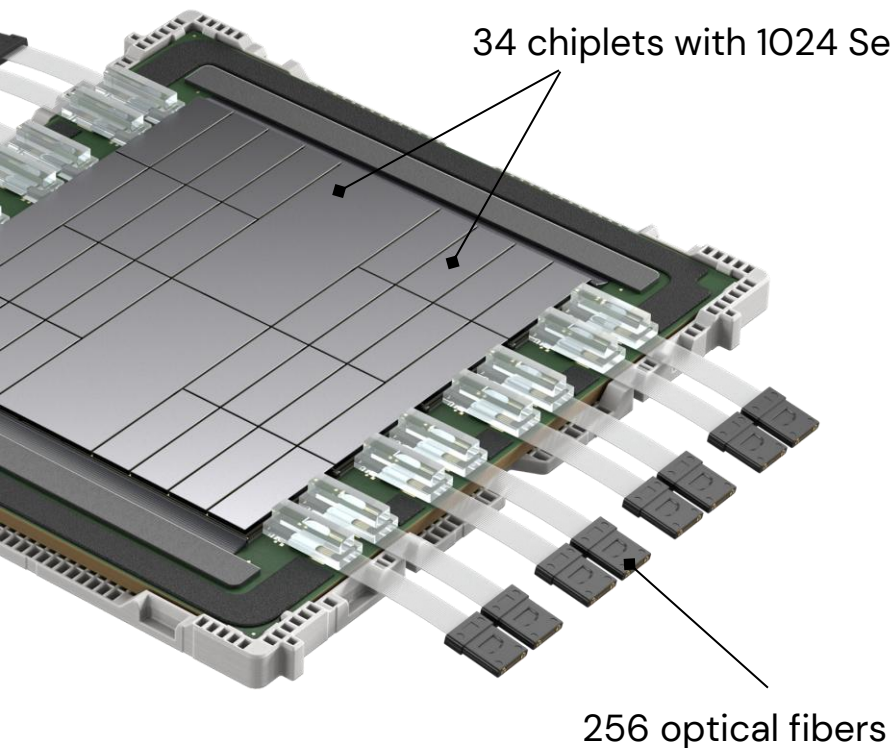


Passage M1000

A 3D photonic “superchip” platform



Unprecedented performance and scale

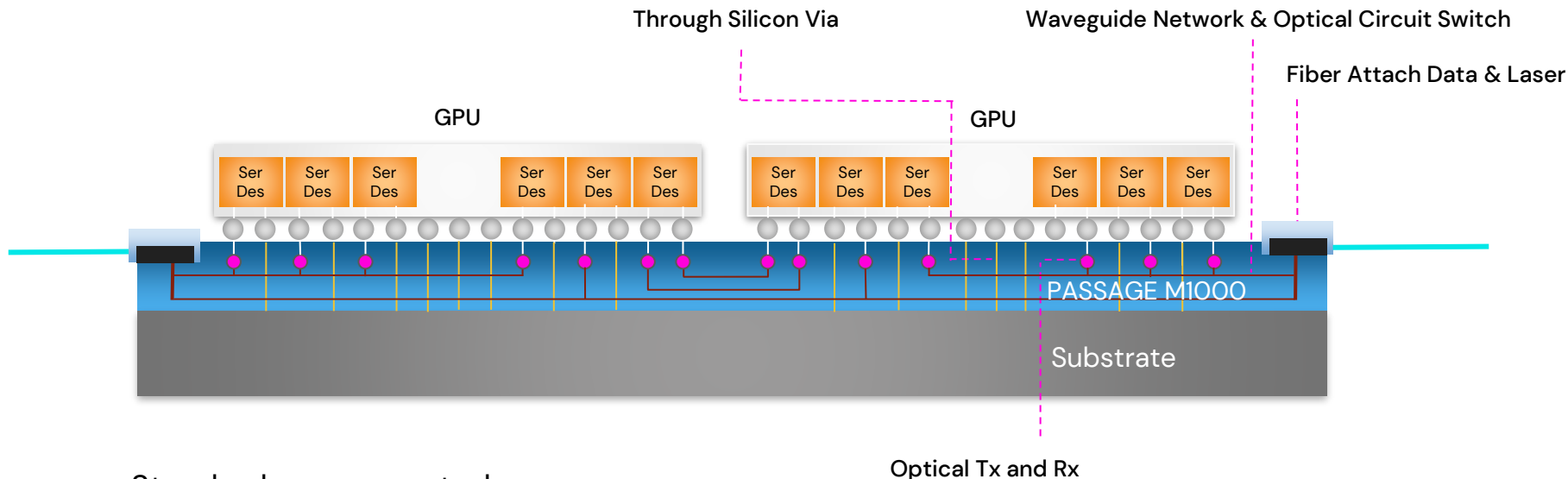


Specifications	
Bandwidth (Tx + Rx)	Up to 114 Tbps
# of SerDes	1024
Silicon die Complex	4,000 mm ²
Power delivery	>1.4 W/mm ² density
Fibers	256
Redundancy	Optical circuit switching

Platform deep dive

Architecture, performance,
and key features.

3D stacking requires compact optical Tx and Rx



Standard processes today

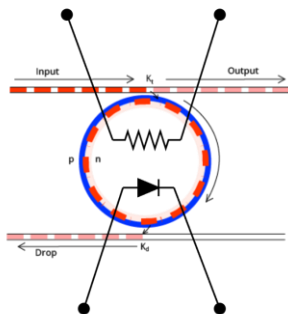
Bump pitch: $\sim 120\text{ }\mu\text{m}$

Bump size: $\sim 80 \mu\text{m}$

Area for a transmitter/receiver: 0.015 mm²

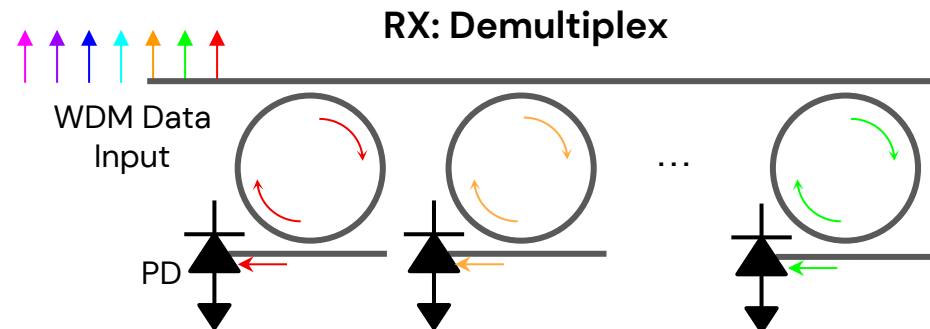
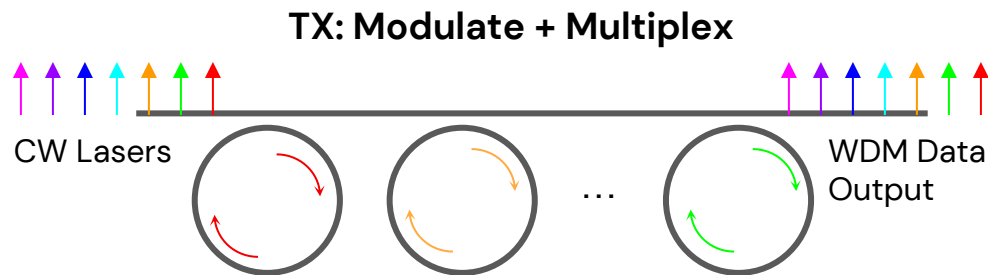
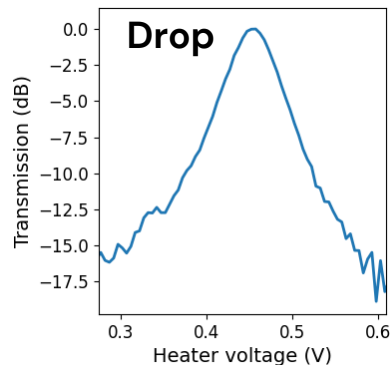
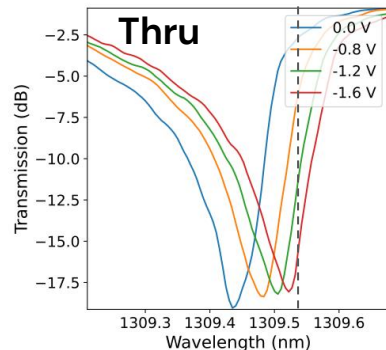
The heart of the engine: silicon microrings

Ultra-compact, high-speed, WDM-friendly



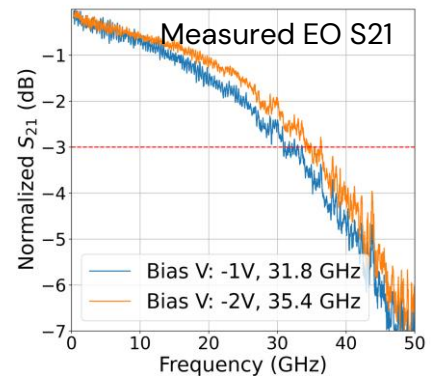
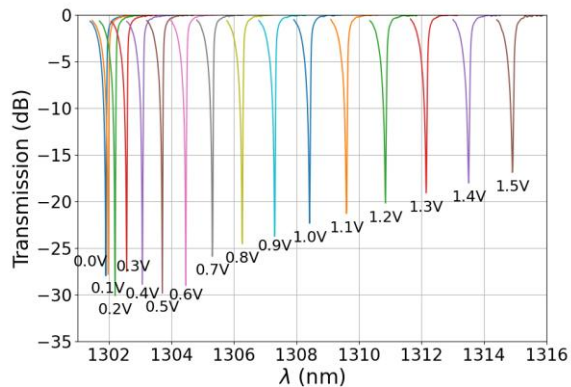
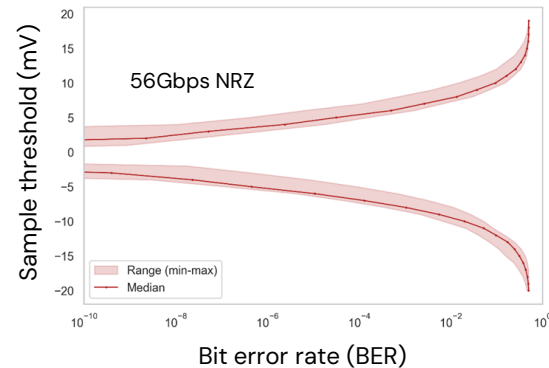
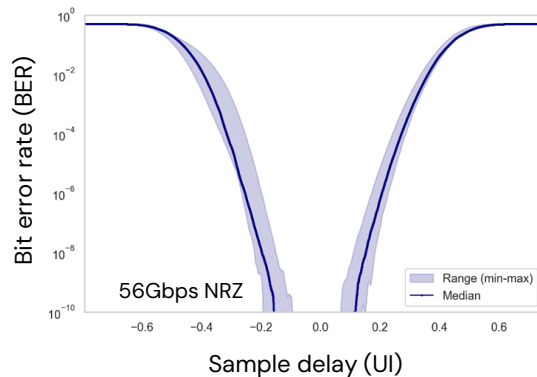
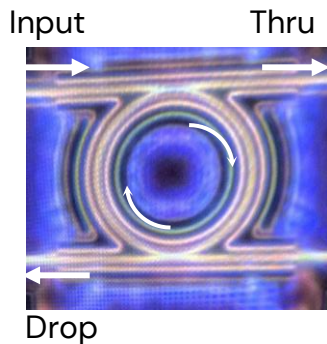
Diameter ~ 15μm

Resistive heater
for tuning
Depletion PN junction
for modulation

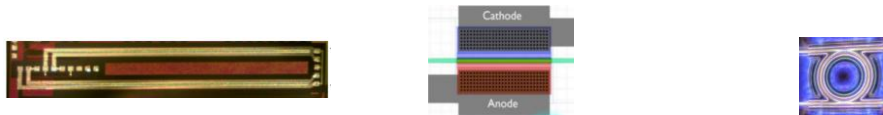


Ultracompact transmitter and receiver

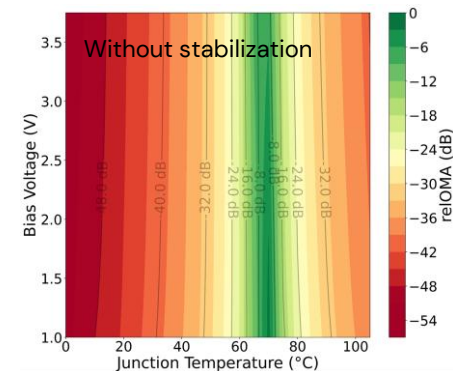
Microrings with inductorless driver and analog front end enable **0.006 mm²** Tx + Rx area.



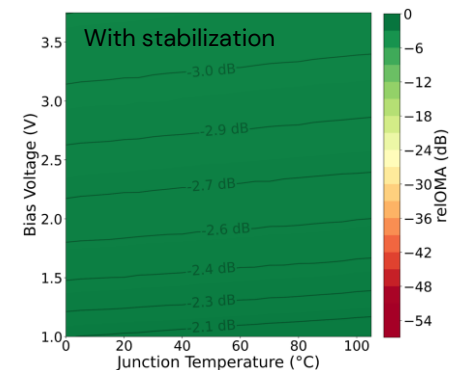
Why rings are revolutionizing photonics



Metric	MZM [1]	SiGe/Ge EAM [2, 3]	MRM [4]
3D-CPO compatible?	No, too large. >1000 μ m	No, too large. 50–100 μ m	Yes, ~15 μ m in diameter.
Need another multiplexer?	Yes	Yes	No, already a multiplexer
Thermal stability	Stable, only thermal gradient between the two arms affect.	Stable with feedback loop. Modulation is temperature dependent.	Stable with feedback loop. Transmission depends on ring resonance.
Power consumption [5]	~50 mW	~10 mW	~1 mW
Transmitter penalty	<5 dB	<10 dB	<5 dB
Optical bands	O-band & C-band	C-band only	O-band & C-band



Feedback control loop gives the MRM a wide operating range: 0°C–105°C



- [1] M. Streshinsky, et al. Opt. Express 21, 30350–30357 (2013).
 [2] J. Fujikata, et al., Opt. Express 31, 10732–10743 (2023).
 [3] Y. Liu, et al., PRJ 8, 1474 (2023).
 [4] E. Timurdogan, et al. Nature Communications 5, 4008 (2014).
 [5] DAB Miller, et al. Opt. Express 20, A293–A308 (2012).

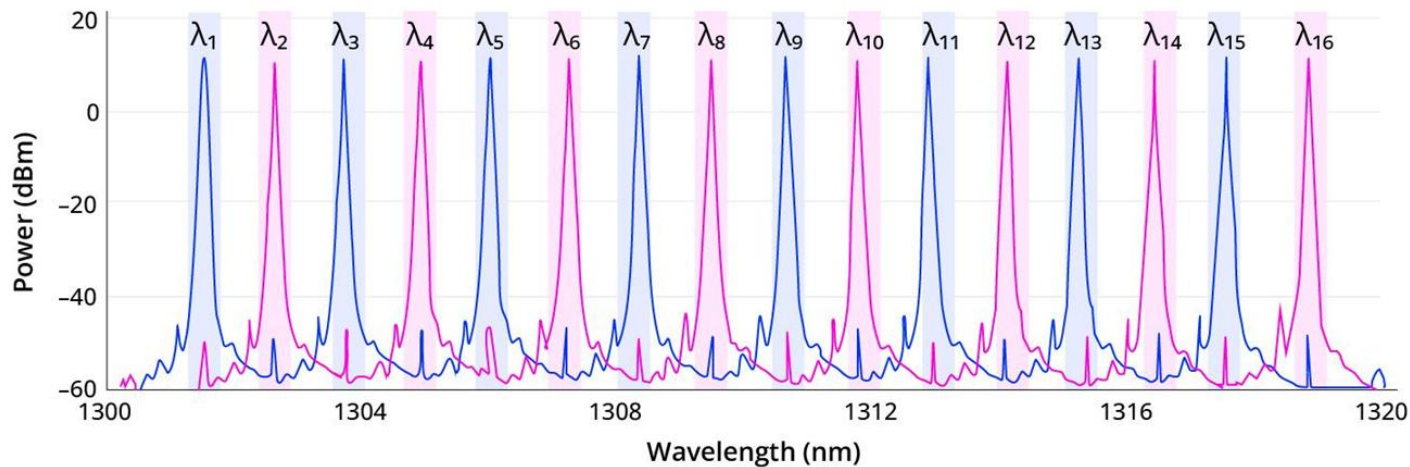
Note: "Relative OMA" (reOMA) is relative to 1 mW laser into the MRM.

Guide™: External WDM laser

Up to 16 wavelengths per fiber, 200 GHz grid

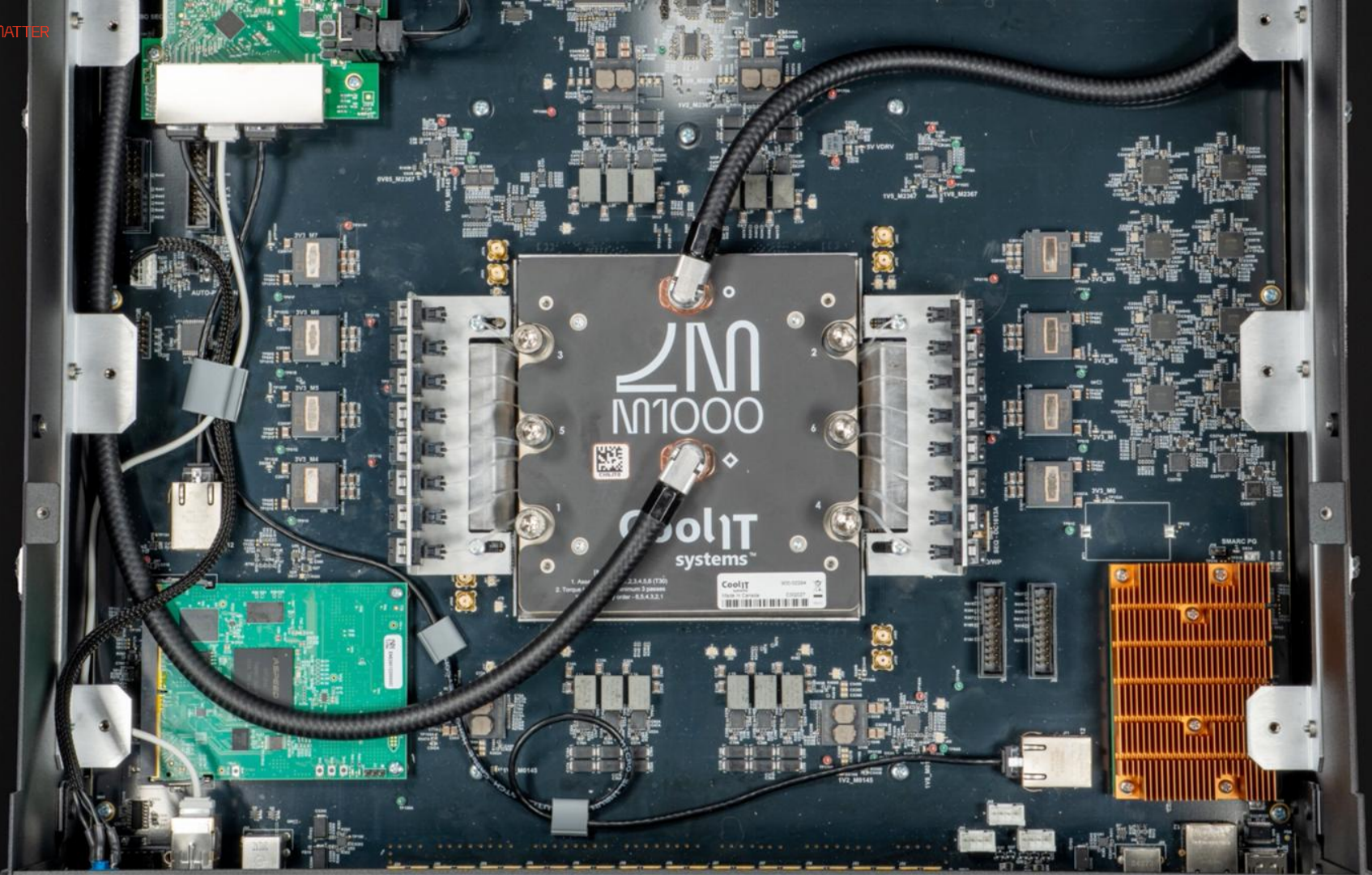
16 fiber output

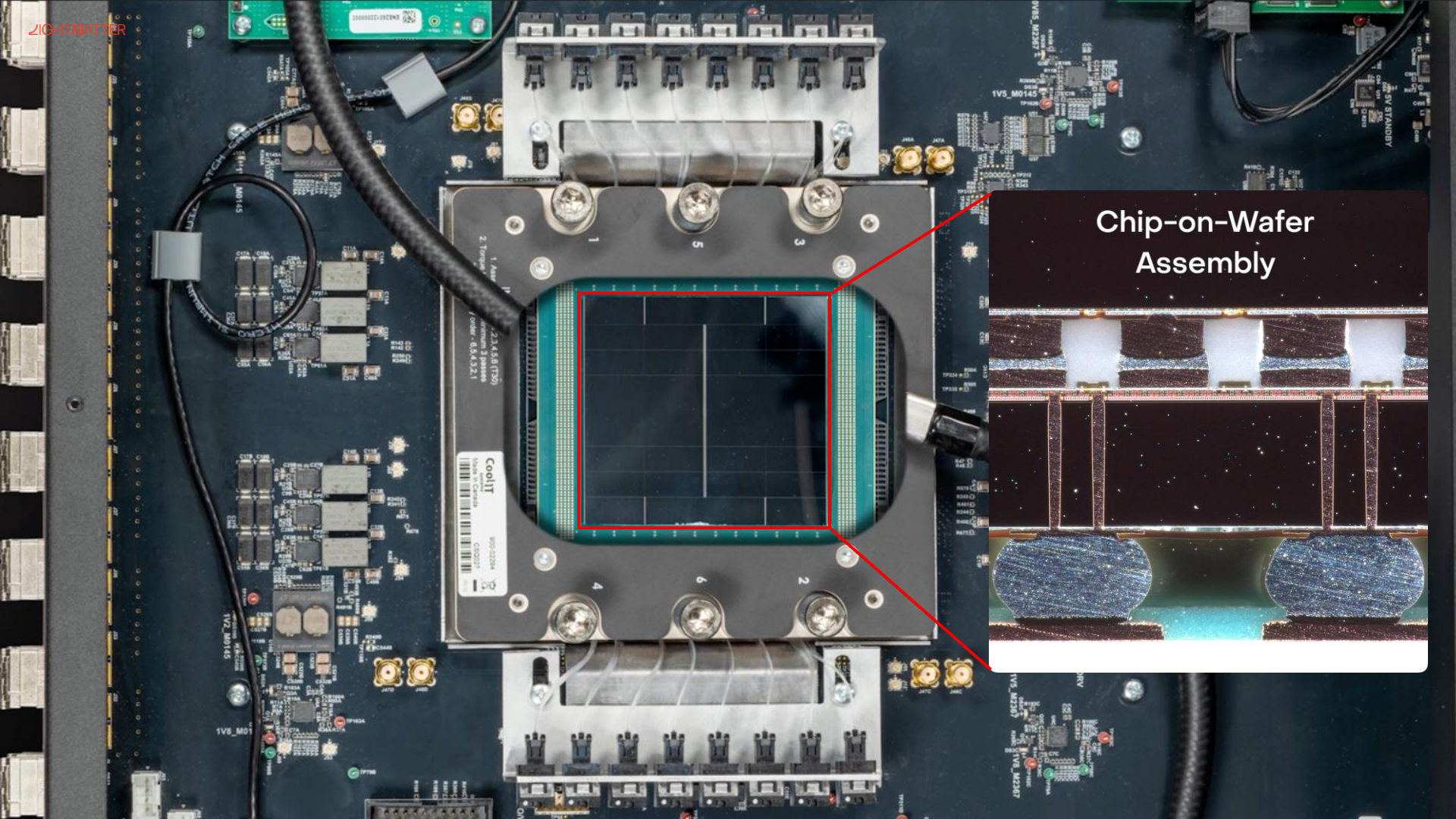
Optimized for microring modulator Tx architectures



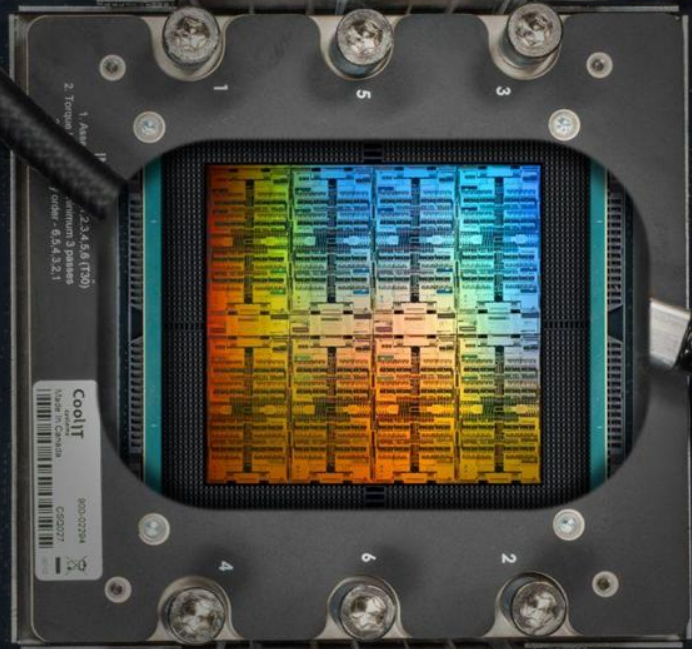


A complete
reference platform



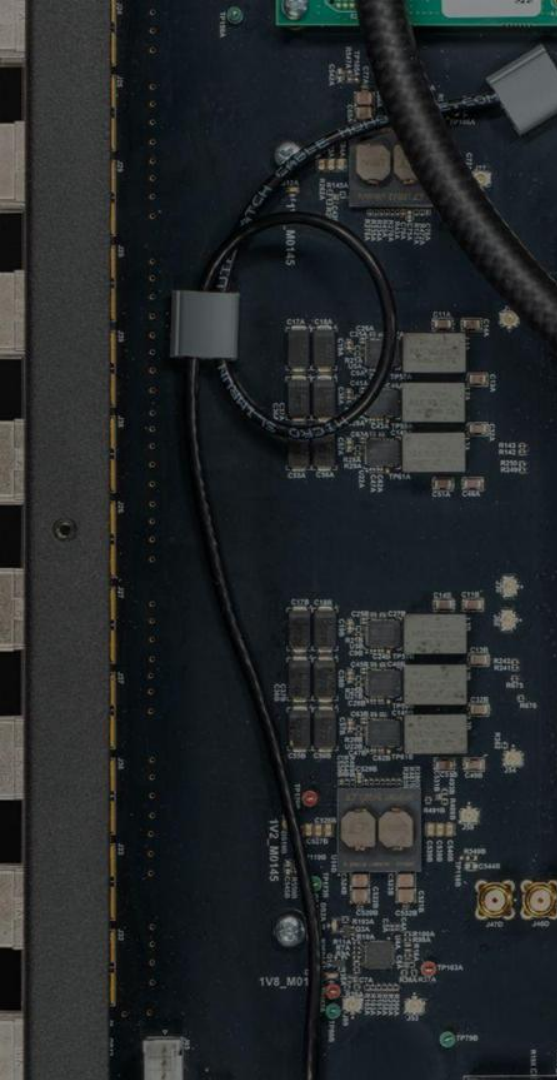
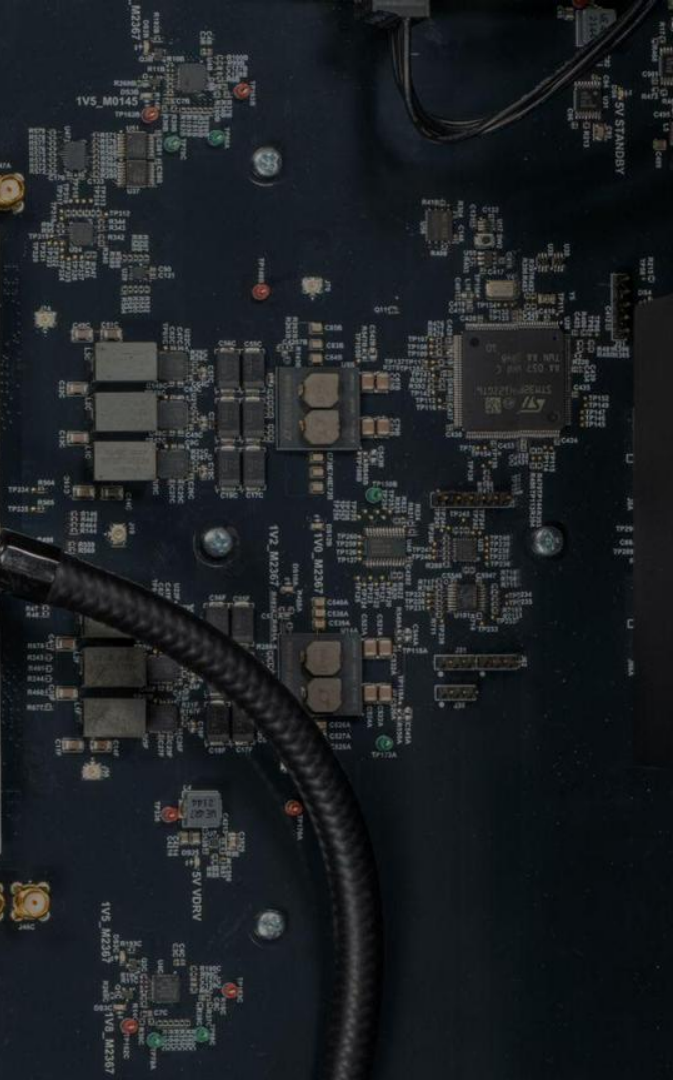


Chip-on-Wafer
Assembly



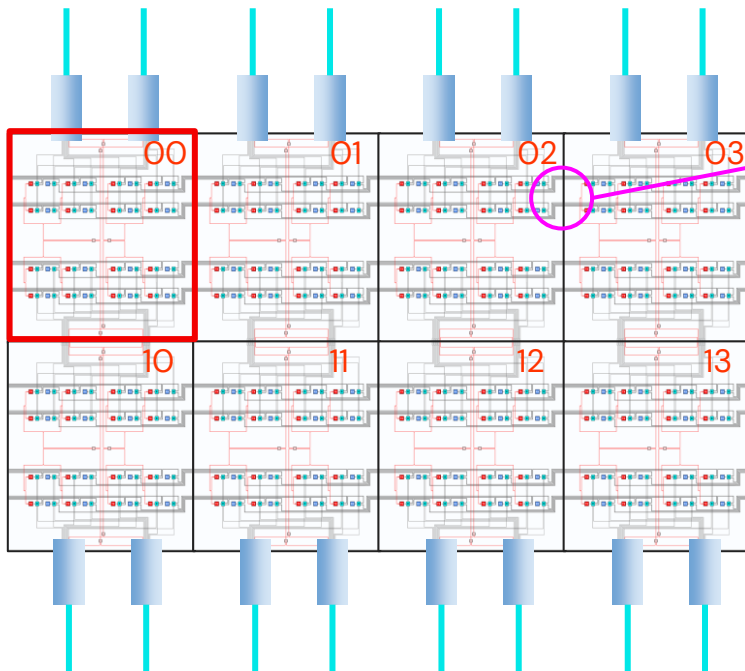
1. Awar
2. Torx
23456 (T30)
Maximum 3 passes
Torque: 0.5-0.521

CoolIT
Made in Canada
980-02294
C22027

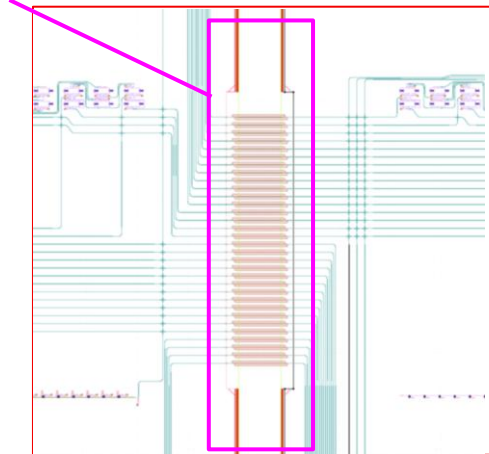


Reconfigurable connectivity

A dynamic, programmable optical fabric in the 2x4 tile design



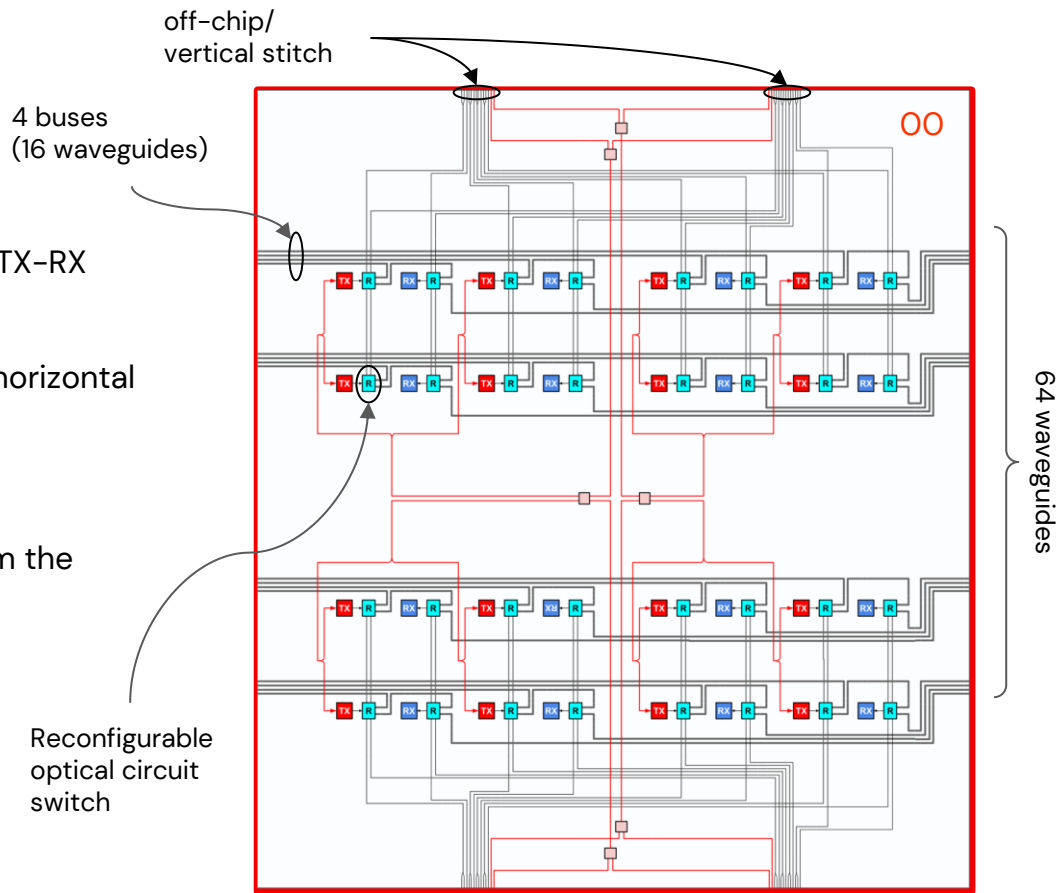
Photonic cross-reticle stitching



Passage M1000
2x4 tile

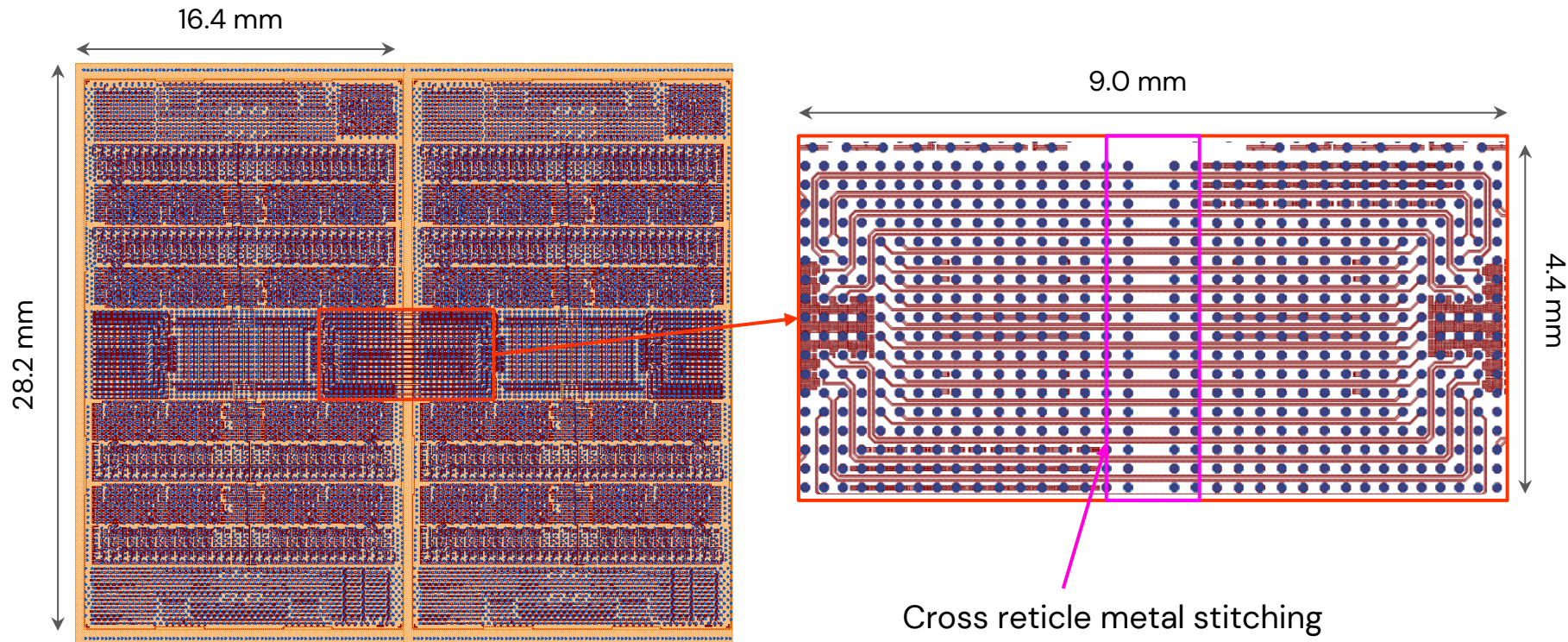
Tile design

- 16 horizontal buses
- Each bus supports up to 2 full-duplex TX-RX links:
 - 8λ @ 56Gbps/ λ per link
- Each TX bank can also talk across the horizontal tile edge to:
 - RX bank on adjacent tile
 - Off-chip
- Each RX bank can receive off-chip from the horizontal tile edge



One single tile

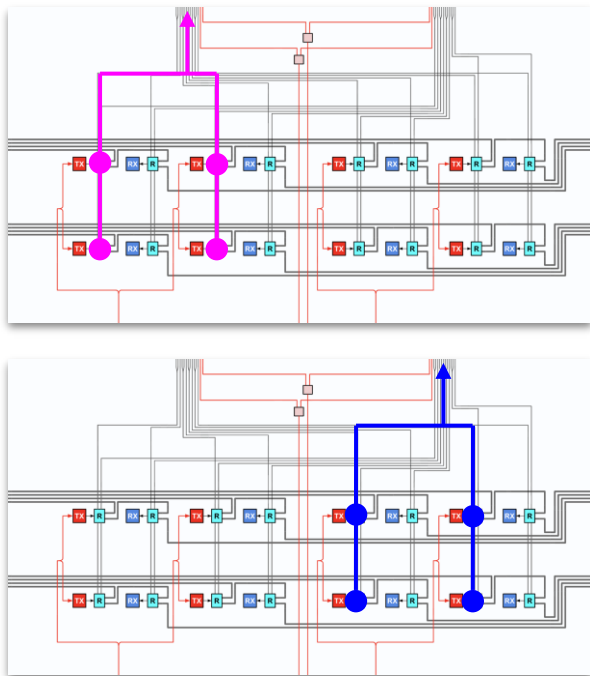
Neighboring tiles can also communicate electrically



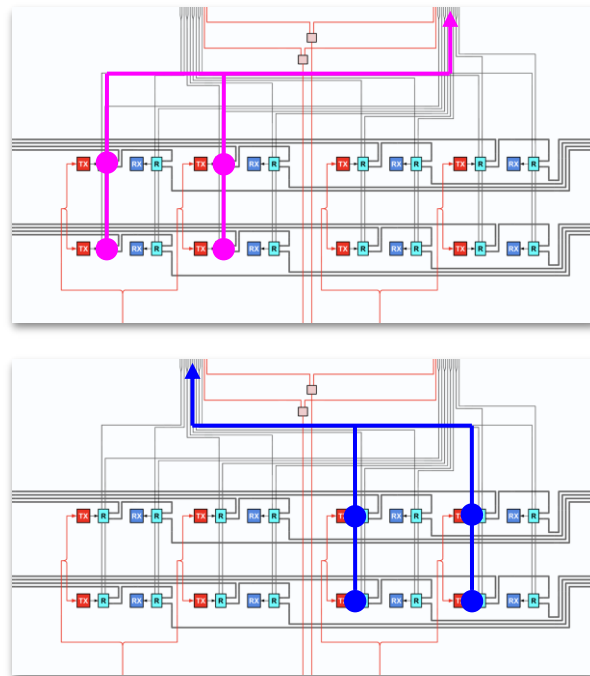
Resilience through optical circuit switching

Fiber attach redundancy allows users to route around failures

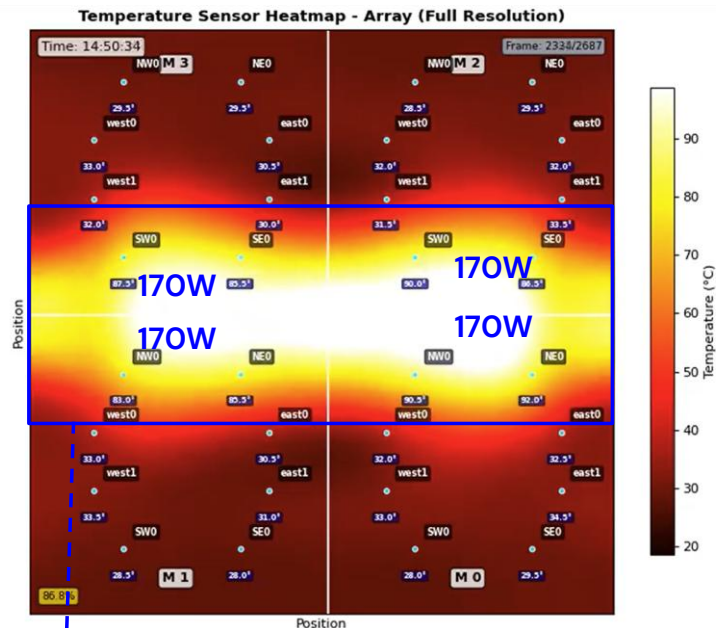
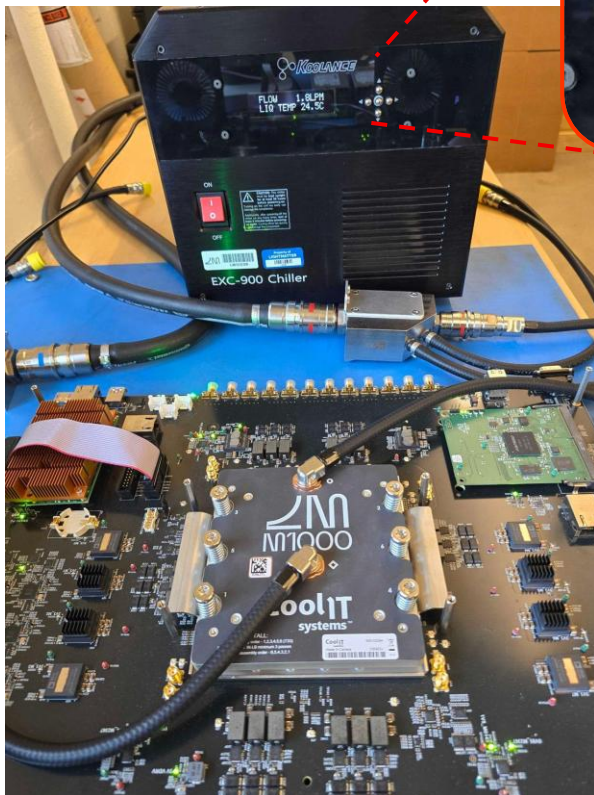
Option A (default):



Option B (backup):

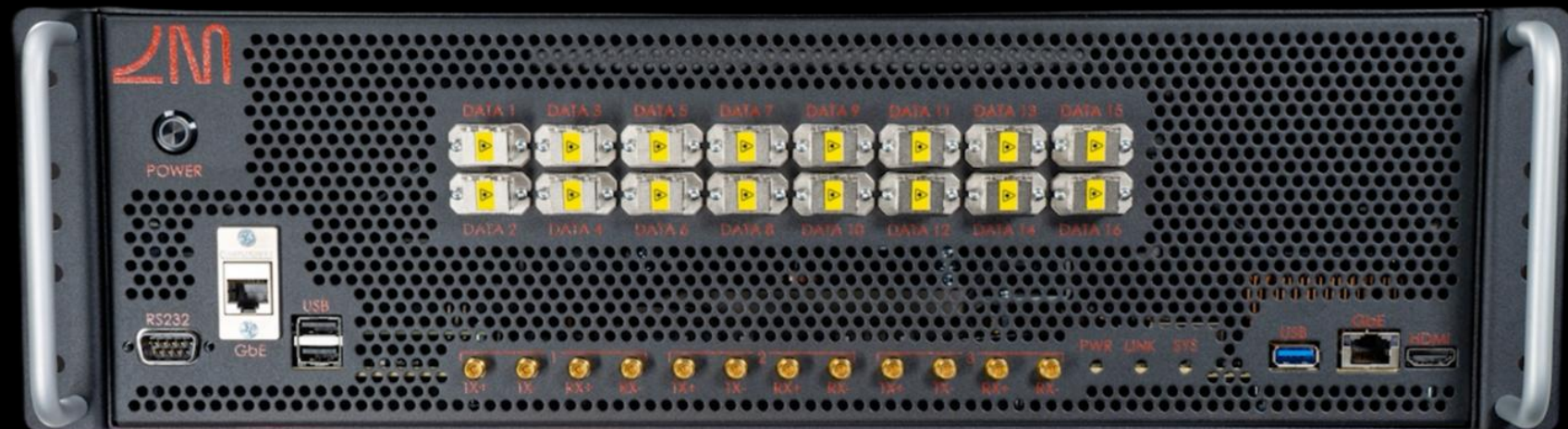


Power delivery and thermal load



369mm² thermal test chip, power density 1.47W/mm².
Passage TSVs support >2.5A/mm².







Bandwidth density leadership

SerDes eye diagrams

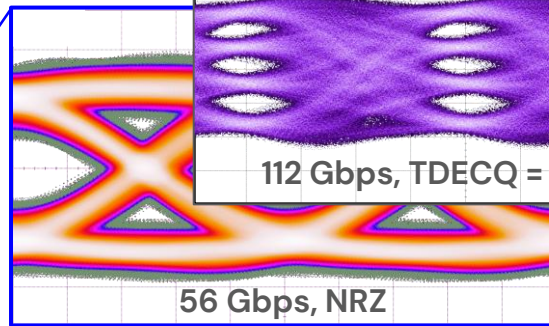
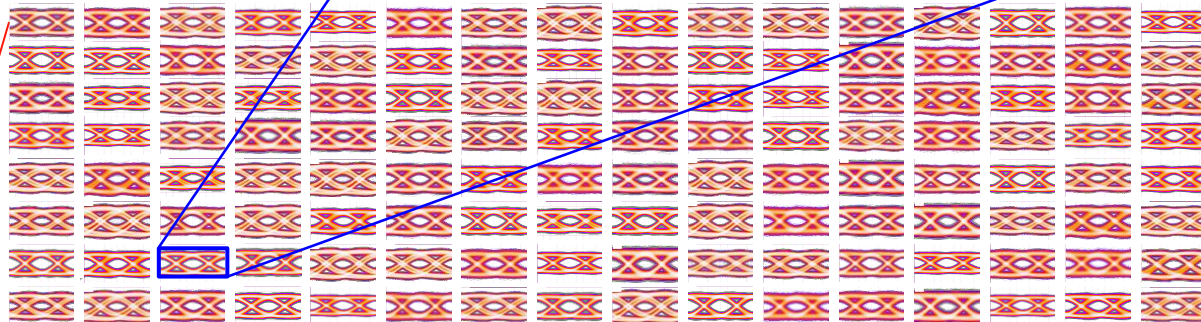
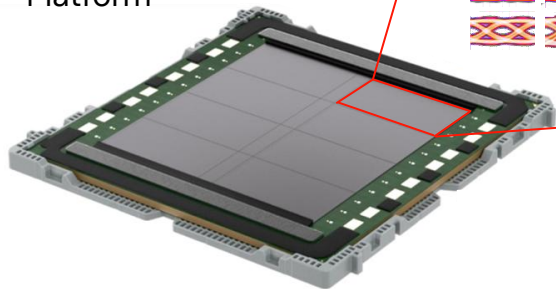
PAM4 also enabled

112 Gbps, TDECQ = 0.83 dB

56 Gbps, NRZ

128 SerDes per tile

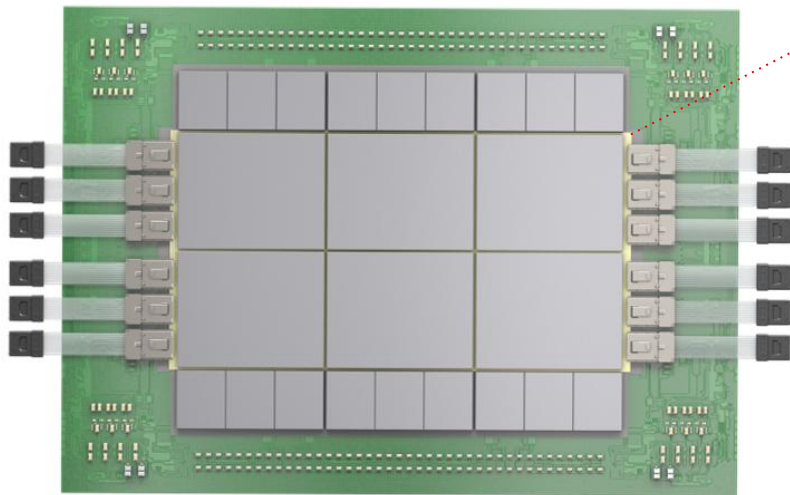
Passage M1000
Platform



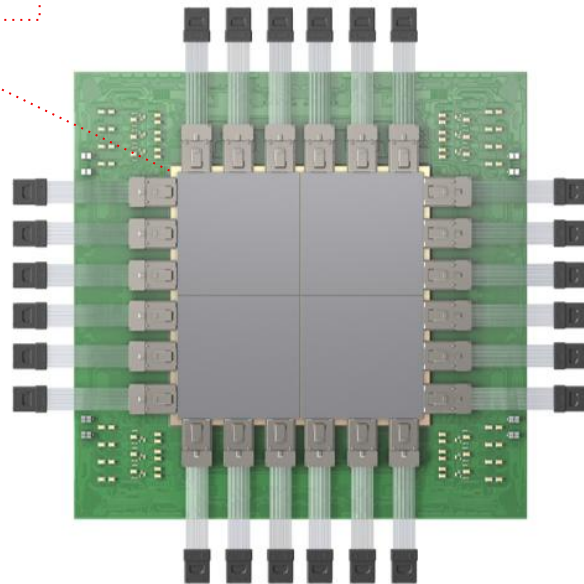
3D Interposer scale-up and out to 1M nodes

The M1000 revolution

Passage M-Series
3D photonic interposer



200 Tbps XPU



400 Tbps Switch

Optimized end-to-end and production-ready

